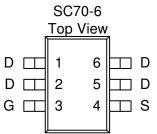
Analog Power AM1432NE

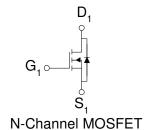
## N-Channel 30V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY					
$V_{DS}(V)$	$V_{DS}(V) = r_{DS(on)}(\Omega)$				
30	$0.033 @ V_{GS} = 10 V$	5.7			
	$0.045 @ V_{GS} = 4.5V$	4.9			

- $\begin{tabular}{ll} \textbf{Low} & r_{DS(on)} \ provides \ higher \ efficiency \ and \\ extends \ battery \ life \end{tabular}$
- Low thermal impedance copper leadframe SC70-6 saves board space
- Fast switching speed
- High performance trench technology





### Protected

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Maximum Unit				
Drain-Source Voltage			30	V		
Gate-Source Voltage			±20	v		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	  T_	5.7			
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	П	4.6	A		
Pulsed Drain Current <sup>b</sup>	ed Drain Current <sup>b</sup>		±20			
Continuous Source Current (Diode Conduction) <sup>a</sup>			1.6	A		
Bowen Dissination <sup>a</sup>	T <sub>A</sub> =25°C	$P_{\mathrm{D}}$	1.56	$\mid$ w $\mid$		
Power Dissipation <sup>a</sup>	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	Гр	0.81	**		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C		

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Maximum	Units			
M · I · · a	t <= 5 sec	D	100	0CM1		
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State	$R_{THJA}$	166	] C/W		

1

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)							
Danamatan	Crush al	T-4 C-2 14	Limits			Unit	
Parameter	Symbol Test Conditions		Min	Тур	Max	K Omt	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1			V	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±10	μΑ	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ	
Zero Gate Voltage Drain Current	*D88	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10		
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	10			A	
Drain-Source On-Resistance <sup>A</sup>		$r_{DS(on)}$ $V_{GS} = 10 \text{ V}, I_D = 1 \text{ A}$ $V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$			33	mΩ	
Dram-Source On-Resistance	<sup>1</sup> DS(on)				45		
Forward Tranconductance <sup>A</sup>	$g_{ m fs}$	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ A}$		11.3		S	
Diode Forward Voltage	$V_{SD}$	$I_S = 1 A, V_{GS} = 0 V$		0.75		V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_{\mathrm{g}}$			4			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 1 \text{ A}$		1		nC	
Gate-Drain Charge	$Q_{\mathrm{gd}}$			1			
Turn-On Delay Time	$t_{d(on)}$			4			
Rise Time	$t_{\rm r}$	$V_{DD} = 10 \text{ V},  R_L = 15 \Omega,  I_D = 1 \text{ A},$		10		ne	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 4.5 \text{ V}$		20		ns	
Fall-Time	$t_{\mathrm{f}}$			10			

#### Notes

a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .

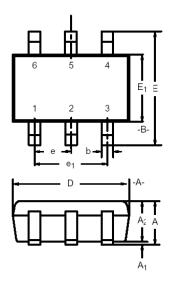
b. Guaranteed by design, not subject to production testing.

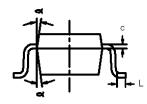
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# Package Information

**SC-70: 6LEAD** 





	MILLIMETERS			INCHES		
Dim	Min	Nom	Мах	Min	Nom	Max
Α	0.90	_	1.10	0.035	_	0.043
A <sub>1</sub>	_	_	0.10	_	_	0.004
A <sub>2</sub>	0.80	_	1.00	0.031	_	0.039
b	0.15	_	0.30	0.006	_	0.012
С	0.10	-	0.25	0.004	_	0.010
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E <sub>1</sub>	1.15	1.25	1.35	0.045	0.049	0.053
е	0.65BSC				0.026BSC	;
e <sub>1</sub>	1.20	1.30	1.40	0.047	0.051	0.055
L	0.10	0.20	0.30	0.004	0.008	0.012
4	7°Nom 7°Nom					